

AO4425 38V P-Channel MOSFET

General Description

The AO4425 uses advanced trench technology to provide excellent $R_{\text{DS(ON)}}$, and ultra-low low gate charge with a 25V gate rating. This device is suitable for use as a load switch or in PWM applications. It is ESD protected.

Product Summary

 $V_{DS}(V) = -38V$

 $I_D = -14A (V_{GS} = -20V)$

 $R_{DS(ON)}$ < 10m Ω (V_{GS} = -20V)

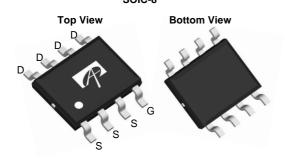
 $R_{DS(ON)}$ < 11m Ω (V_{GS} = -10V) ESD Rating: 4000V HBM

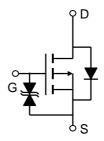
LOD Rating. 4000 V TID

100% UIS Tested 100% Rg Tested









| | | Absolute Maxir | num Ratings | T _^ =25℃ unless | otherwise noted |
|--|--|----------------|-------------|----------------------------|-----------------|
|--|--|----------------|-------------|----------------------------|-----------------|

| Parameter | | Symbol | Maximum | Units | |
|---|---------------------|-------------------|------------|-------|--|
| Drain-Source Voltage | | V_{DS} | -38 | V | |
| Gate-Source Voltage | | V_{GS} | ±25 | V | |
| Continuous Drain | T _A =25℃ | | -14 | | |
| Current ^A | T _A =70℃ | I_D | -11 | Α | |
| Pulsed Drain Current ^B | | I _{DM} | -50 | | |
| Power Dissipation A $T_A=25$ °C $T_A=70$ °C | | В | 3.1 | - W | |
| | | $-P_D$ | 2 | | |
| Junction and Storage Temperature Range | | T_J , T_{STG} | -55 to 150 | C | |

| Thermal Characteristics | | | | | | |
|---------------------------------------|--------------|--------------------|-----|-------|-----|--|
| Parameter | Symbol | Тур | Max | Units | | |
| Maximum Junction-to-Ambient A | t ≤ 10s | $R_{\theta JA}$ | 26 | 40 | ℃/W | |
| Maximum Junction-to-Ambient A | Steady-State | IN _θ JA | 50 | 75 | ℃/W | |
| Maximum Junction-to-Lead ^C | Steady-State | $R_{	heta JL}$ | 14 | 24 | ℃/W | |

Electrical Characteristics (T_J=25℃ unless otherwise noted)

| Symbol | pol Parameter Conditions | | Min | Тур | Max | Units | |
|---------------------|-------------------------------------|--|-----|------|------|-------|--|
| STATIC F | PARAMETERS | | | | | | |
| BV _{DSS} | Drain-Source Breakdown Voltage | $I_D = -250 \mu A, V_{GS} = 0 V$ | -38 | | | V | |
| | Zoro Coto Voltago Droin Current | V_{DS} =-30V, V_{GS} =0V | | | -100 | nA | |
| I _{DSS} | Zero Gate Voltage Drain Current | | | | -500 | IIA | |
| lana | Gate-Body leakage current | V_{DS} =0V, V_{GS} =±20V | | | ±1 | μΑ | |
| I _{GSS} | Gate-Body leakage current | V_{DS} =0V, V_{GS} =±25V | | | ±10 | μΑ | |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{DS}=V_{GS}$ $I_{D}=-250\mu A$ | -2 | -2.5 | -3.5 | V | |
| $I_{D(ON)}$ | On state drain current | V_{GS} =-10V, V_{DS} =-5V | -50 | | | Α | |
| | Static Drain-Source On-Resistance | V _{GS} =-20V, I _D =-14A | | 7.7 | 10 | mΩ | |
| R _{DS(ON)} | | T _J =125℃ | | 11 | 13.5 | 11122 | |
| | | V _{GS} =-10V, I _D =-14A | | 8.8 | 11 | mΩ | |
| g _{FS} | Forward Transconductance | V_{DS} =-5V, I_{D} =-14A | | 43 | | S | |
| V_{SD} | Diode Forward Voltage | I_S =-1A, V_{GS} =0V | | 0.71 | 1 | V | |
| I _S | Maximum Body-Diode Continuous Curre | ent | | | 4.2 | Α | |
| DYNAMIC | CPARAMETERS | | | | | | |
| C_{iss} | Input Capacitance | | | 3800 | | pF | |
| C _{oss} | Output Capacitance | V_{GS} =0V, V_{DS} =-20V, f=1MHz | | 560 | | pF | |
| C _{rss} | Reverse Transfer Capacitance | | | 350 | | pF | |
| R_g | Gate resistance | V_{GS} =0V, V_{DS} =0V, f=1MHz | | 7.5 | | Ω | |
| SWITCHI | NG PARAMETERS | | | | | | |
| Q_g | Total Gate Charge | | | 63 | | nC | |
| Q_{gs} | Gate Source Charge | V_{GS} =-10V, V_{DS} =-20V, I_D =-14A | | 14.1 | | nC | |
| Q_{gd} | Gate Drain Charge | | | 16.1 | | nC | |
| t _{D(on)} | Turn-On DelayTime | | | 12.4 | | ns | |
| t _r | Turn-On Rise Time | V_{GS} =-10V, V_{DS} =-20V, R_L =1.35 Ω , | | 9.2 | | ns | |
| $t_{D(off)}$ | Turn-Off DelayTime | ayTime $R_{GEN}=3\Omega$ | | 97.5 | | ns | |
| t _f | Turn-Off Fall Time | | | 45.5 | | ns | |
| t _{rr} | Body Diode Reverse Recovery Time | I _F =-14A, dI/dt=100A/μs | | 35 | | ns | |
| Q _{rr} | Body Diode Reverse Recovery Charge | I _F =-14A, dI/dt=100A/μs | | 33 | | nC | |

A: The value of R $_{\theta JA}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T $_A$ =25 $^{\circ}$ C.

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The value in any given application depends on the user's specific board design. The current rating is based on the t \leq 10s thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The R $_{\theta JA}$ is the sum of the thermal impedence from junction to lead R $_{\theta JL}$ and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using $<300~\mu s$ pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in ² FR-4 board with 2oz. Copper, in a still air environment with T_A=25°C. The SOA curve provides a single pulse rating.

TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

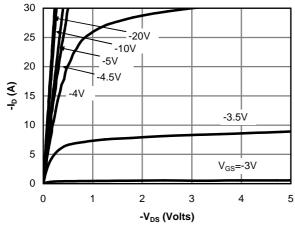


Fig 1: On-Region Characteristics

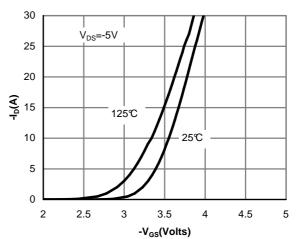


Figure 2: Transfer Characteristics

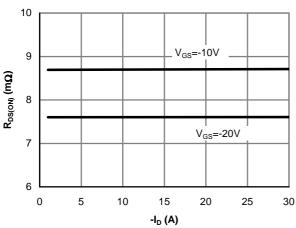


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

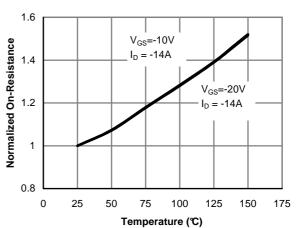


Figure 4: On-Resistance vs. Junction Temperature

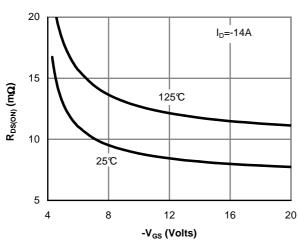


Figure 5: On-Resistance vs. Gate-Source Voltage

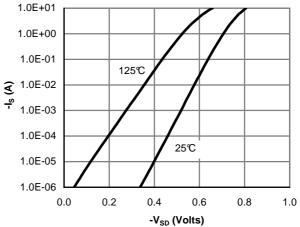
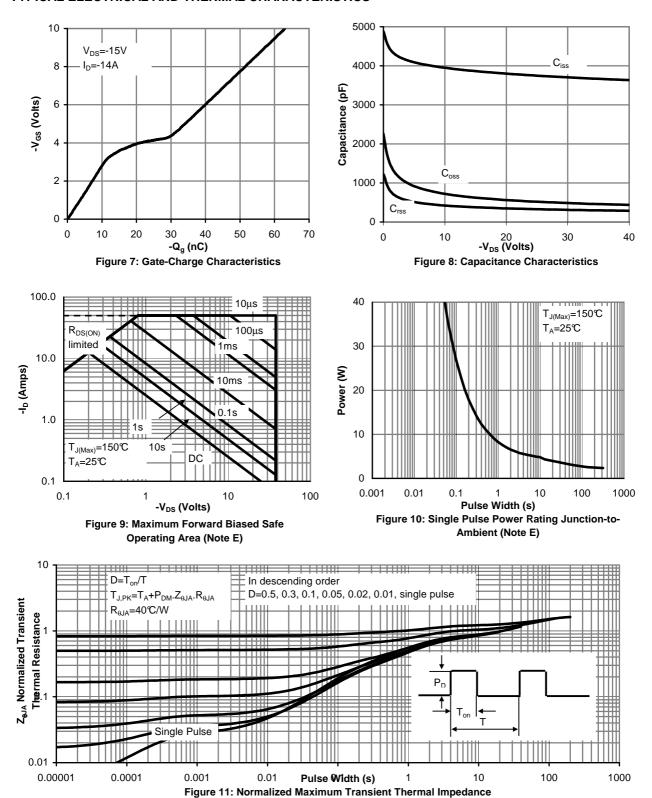


Figure 6: Body-Diode Characteristics

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